DATASHEET

Description

The 9DBU0831 is a member of IDT's 1.5V Ultra-Low-Power (ULP) PCIe family. The device has 8 output enables for clock management and 3 selectable SMBus addresses.

Recommended Application

1.5V PCIe Gen1-2-3 Zero Delay/Fanout Buffer (ZDB/FOB)

Output Features

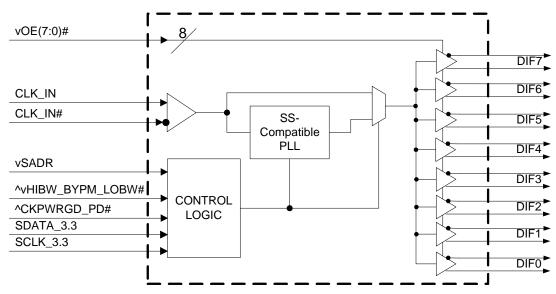
• 8 – 1-167MHz Low-Power (LP) HCSL DIF pairs

Key Specifications

- DIF cycle-to-cycle jitter <50ps
- DIF output-to-output skew < 75ps
- DIF phase jitter is PCIe Gen1-2-3 compliant
- DIF bypass mode *additive* phase jitter is <300fs rms for PCIe Gen3
- DIF bypass mode additive phase jitter <350fs rms for 12k-20MHz

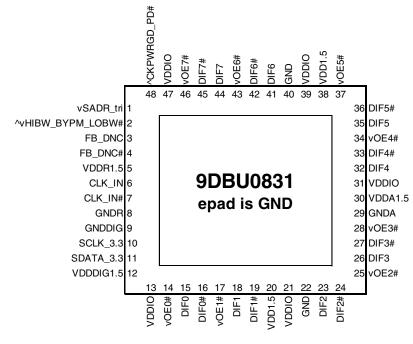
Features/Benefits

- LP-HCSL outputs; save 16 resistors compared to standard HCSL outputs
- 53mW typical power consumption in PLL mode; eliminates thermal concerns
- Outputs can optionally be supplied from any voltage between 1.05 and 1.5V; maximum power savings
- Spread Spectrum (SS) compatible; allows SS for EMI reduction
- OE# pins; support DIF power management
- HCSL-compatible differential input; can be driven by common clock sources
- SMBus-selectable features; optimize signal integrity to application
 - slew rate for each output
 - differential output amplitude
- Pin/SMBus selectable PLL bandwidth and PLL Bypass; optimize PLL to application
- Outputs blocked until PLL is locked; clean system start-up
- Device contains default configuration; SMBus interface not required for device control
- Three selectable SMBus addresses; multiple devices can easily share an SMBus segment
- 3.3V tolerant SMBus interface works with legacy controllers
- Space saving 48-pin 6x6mm VFQFPN; minimal board space



Block Diagram

Pin Configuration



48-pin MLF, 6x6 mm, 0.4mm pitch

^v prefix indicates internal 120KOhm pull up AND pull down resistor (biased to VDD/2)

v prefix indicates internal 120KOhm pull down resistor

^ prefix indicates internal 120KOhm pull up resistor

SMBus Address Selection Table

	SADR	Address	+ Read/Write bit
State of SADR on first application of	0	1101011	X
CKPWRGD PD#	М	1101100	X
	1	1101101	х

Power Management Table

CKPWRGD PD#	CLK IN	SMBus	SMBus OEx# Pin D		x	PLL
		OEx bit		True O/P	Comp. O/P	FLL
0	Х	Х	Х	Low	Low	Off
1	Running	0	Х	Low	Low	On ¹
1	Running	1	0	Running	Running	On ¹
1	Running	1	1	Low	Low	On ¹

1. If Bypass mode is selected, the PLL will be off, and outputs will be running.

Power Connections

Pin Number			Description
VDD	VDDIO	GND	Description
			Input
5		8	receiver
			analog
12		9	Digital Power
20,31,38	13,21,31,39, 47	22,29,40	DIF outputs
30		29	PLL Analog

Note: epad on this device is not electrically connected to the die. It should be connected to ground for best thermal performance.

PLL Operating Mode

		Byte1 [7:6]	Byte1 [4:3]
HiBW_BypM_LoBW#	MODE	Readback	Control
0	PLL Lo BW	00	00
М	Bypass	01	01
1	PLL Hi BW	11	11

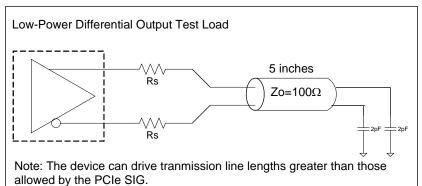
Pin Descriptions

PIN #	PIN NAME	TYPE	DESCRIPTION
1	vSADR_tri	LATCHED	Tri-level latch to select SMBus Address. See SMBus Address Selection Table.
· ·		IN	
2	^vHIBW_BYPM_LOBW#	LATCHED	Trilevel input to select High BW, Bypass or Low BW mode.
		IN	See PLL Operating Mode Table for Details.
3	FB_DNC	DNC	True clock of differential feedback. The feedback output and feedback input are
0		BNO	connected internally on this pin. Do not connect anything to this pin.
4			Complement clock of differential feedback. The feedback output and feedback
4	FB_DNC#	DNC	input are connected internally on this pin. Do not connect anything to this pin.
_			1.5V power for differential input clock (receiver). This VDD should be treated as
5	VDDR1.5	PWR	an Analog power rail and filtered appropriately.
6	CLK_IN	IN	True Input for differential reference clock.
7	 CLK_IN#	IN	Complementary Input for differential reference clock.
8	GNDR	GND	Analog Ground pin for the differential input (receiver)
9	GNDDIG	GND	Ground pin for digital circuitry
10	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
11	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
12	VDDDIG1.5	PWR	1.5V digital power (dirty power)
13	VDDIO	PWR	Power supply for differential outputs
	050"		Active low input for enabling DIF pair 0. This pin has an internal pull-down.
14	vOE0#	IN	1 =disable outputs, 0 = enable outputs
15	DIF0	OUT	Differential true clock output
16	DIF0#	OUT	Differential Complementary clock output
			Active low input for enabling DIF pair 1. This pin has an internal pull-down.
17	vOE1#	IN	1 =disable outputs, 0 = enable outputs
18	DIF1	OUT	Differential true clock output
19	DIF1#	OUT	Differential Complementary clock output
20	VDD1.5	PWR	Power supply, nominally 1.5V
21	VDDIO	PWR	Power supply for differential outputs
22	GND	GND	Ground pin.
23	DIF2	OUT	Differential true clock output
24	DIF2#	OUT	Differential Complementary clock output
0.5	050"	18.1	Active low input for enabling DIF pair 2. This pin has an internal pull-down.
25	vOE2#	IN	1 =disable outputs, 0 = enable outputs
26	DIF3	OUT	Differential true clock output
27	DIF3#	OUT	Differential Complementary clock output
20		INI	Active low input for enabling DIF pair 3. This pin has an internal pull-down.
28	vOE3#	IN	1 =disable outputs, 0 = enable outputs
29	GNDA	GND	Ground pin for the PLL core.
30	VDDA1.5	PWR	1.5V power for the PLL core.
31	VDDIO	PWR	Power supply for differential outputs
32	DIF4	OUT	Differential true clock output
33	DIF4#	OUT	Differential Complementary clock output
34	vOE4#	IN	Active low input for enabling DIF pair 4. This pin has an internal pull-down.
- 34		11N	1 =disable outputs, 0 = enable outputs
35	DIF5	OUT	Differential true clock output
36	DIF5#	OUT	Differential Complementary clock output
37	vOE5#	IN	Active low input for enabling DIF pair 5. This pin has an internal pull-down.
- 57			1 =disable outputs, 0 = enable outputs
38	VDD1.5	PWR	Power supply, nominally 1.5V
39	VDDIO	PWR	Power supply for differential outputs
40	GND	GND	Ground pin.

Pin Descriptions (cont.)

PIN #	PIN NAME	TYPE	DESCRIPTION
41	DIF6	OUT	Differential true clock output
42	DIF6#	OUT	Differential Complementary clock output
43	vOE6#	IN	Active low input for enabling DIF pair 6. This pin has an internal pull-down.
43	VOL0#		1 =disable outputs, 0 = enable outputs
44	DIF7	OUT	Differential true clock output
45	DIF7#	OUT	Differential Complementary clock output
46	vOE7#	IN	Active low input for enabling DIF pair 7. This pin has an internal pull-down.
40	VOE/#		1 =disable outputs, 0 = enable outputs
47	VDDIO	PWR	Power supply for differential outputs
			Input notifies device to sample latched inputs and start up on first high
48	^CKPWRGD_PD#	IN	assertion. Low enters Power Down Mode, subsequent high assertions exit
			Power Down Mode. This pin has internal pull-up resistor.
49	EPAD	GND	Connect ePAD to ground.

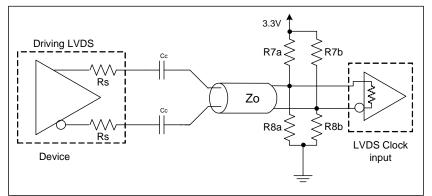
Test Loads



Alternate Differential Output Terminations

Rs	Zo	Units
33	100	Ohms
27	85	Onins

Driving LVDS



Driving LVDS inputs

	`		
	Receiver has	Receiver does not	
Component	termination	have termination	Note
R7a, R7b	10K ohm	140 ohm	
R8a, R8b	5.6K ohm	75 ohm	
Cc	0.1 uF	0.1 uF	
Vcm	1.2 volts	1.2 volts	

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9DBU0831. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx		-0.5		2	V	1,2
Input Voltage	V _{IN}		-0.5		V _{DD} +0.5	V	1,3
Input High Voltage, SMBus	VIHSMB	SMBus clock and data pins			3.3	V	1
Storage Temperature	Ts		-65		150	С°	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 2.0V.

Electrical Characteristics–Clock Input Parameters

TA = T_{AMB}, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Common Mode Voltage - DIF_IN	V _{COM}	Common Mode Input Voltage	200		725	mV	1
Input Swing - DIF_IN	V _{SWING}	Differential value	300		1450	mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}, V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45	50	55	%	1
Input Jitter - Cycle to Cycle	J _{DIFIn}	Differential Measurement	0		150	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

² Slew rate measured through +/-75mV window centered around differential zero

Electrical Characteristics–Input/Supply/Common Parameters–Normal Operating Conditions

TA = T_{AMB}, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Supply voltage for core and analog	1.425	1.5	1.575	V	
Output Supply Voltage	VDDIO	Supply voltage for Low Power HCSL Outputs	0.95	1.05	1.575	V	
Ambient Operating	т	Commmercial range	0	25	70	°C	1
Temperature	T _{AMB}	Industrial range	-40	25	85	°C	1
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus	$0.75 V_{DD}$		$V_{DD} + 0.3$	V	
Input Mid Voltage	VIM	Single-ended tri-level inputs ('_tri' suffix)	0.4 V _{DD}		0.6 V _{DD}	V	
Input Low Voltage	VIL	Single-ended inputs, except SMBus	-0.3		$0.25 V_{DD}$	V	
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	
		Single-ended inputs					
Input Current	I _{INP}	$V_{IN} = 0$ V; Inputs with internal pull-up resistors	-200		200	uA	
		$V_{IN} = VDD$; Inputs with internal pull-down resistors					
	F _{ibyp}	Bypass mode	1		167	MHz	2
Input Frequency	F _{ipll}	100MHz PLL mode	60	100.00	110	MHz	2
Pin Inductance	L _{pin}				7	nH	1
	C _{IN}	Logic Inputs, except DIF_IN	1.5			pF	1
Capacitance	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5			.575 V 70 $^{\circ}$ C 85 $^{\circ}$ C $^{\circ}$ L $^{\circ}$ C <	1,5
	C _{OUT}	Output pin capacitance				· ·	1
		From V _{DD} Power-Up and after input clock					
Clk Stabilization	T _{STAB}	stabilization or de-assertion of PD# to 1st clock			1	pF ms	1,2
Input SS Modulation	4	Allowable Frequency for PCIe Applications	00		00		
Frequency PCIe	f _{MODINPCIe}	(Triangular Modulation)	30		33	KHZ	
Input SS Modulation	f _{MODIN}	Allowable Frequency for non-PCIe Applications	0		66	kH7	
Frequency non-PCIe	MODIN	(Triangular Modulation)	0		00	KI IZ	
OE# Latency	t _{LATOE#}	DIF start after OE# assertion	1		3	clocks	1,3
0 = =	·LATOE#	DIF stop after OE# deassertion			Ŭ	0.00.00	.,0
Tdrive_PD#	t _{DRVPD}	DIF output enable after			300	us	1,3
T f all		PD# de-assertion					
Tfall	t _F	Fall time of single-ended control inputs					2
Trise	t _R	Rise time of single-ended control inputs					2
SMBus Input Low Voltage	VILSMB						
SMBus Input High Voltage	VIHSMB	$V_{DDSMB} = 3.3V$, see note 4 for $V_{DDSMB} < 3.3V$	2.1				4
SMBus Output Low Voltage	V _{OLSMB}	@ I _{PULLUP}			0.4		
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4				
Nominal Bus Voltage	V _{DDSMB}	Bus Voltage	1.425				
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			400	kHz	7

¹Guaranteed by design and characterization, not 100% tested in production.

 $^2\mbox{Control}$ input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

⁴ For $V_{DDSMB} < 3.3V$, $V_{IHSMB} >= 0.8xV_{DDSMB}$

⁵DIF_IN input

⁶The differential input clock must be running for the SMBus to be active

Electrical Characteristics–DIF Low-Power HCSL Outputs

TA = T_{AMB.} Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

AND, THE J	P	a					
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on, fast setting	1.4	2.2	3.5	V/ns	1,2,3
Slew late	dV/dt	Scope averaging on, slow setting	0.9	1.7	2.5	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on		2.7	20	%	1,2,4
Voltage High	V _{HIGH}	Statistical measurement on single-ended signal	630	735	850	mV	7
Voltage Low	V _{LOW}	using oscilloscope math function. (Scope averaging on)		-16	150		7
Max Voltage	Vmax	Measurement on single ended signal using		779	1150	mV	7
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	-45		mv	7
Vswing	Vswing	Scope averaging off	300	1503		mV	1,2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	405	550	mV	1,5
Crossing Voltage (var)	∆-Vcross	Scope averaging off		12	140	mV	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

⁷ At default SMBus settings.

Electrical Characteristics–Current Consumption

TA = T_{AMB}, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I _{DDA}	VDDA+VDDR, PLL Mode, @100MHz		11	15	mA	
	I _{DD}	VDD, All outputs active @100MHz		6	9	mA	
	I _{DDIO}	VDDIO, All outputs active @100MHz		28	35	mA	
Powerdown Current	I _{DDAPD}	VDDA+VDDR, CKPWRGD_PD#=0		0.5	1	mA	2
	I _{DDPD}	VDDx, CKPWRGD_PD#=0		0.6	1	mA	2
	IDDIOPD	VDDIO, CKPWRGD_PD#=0		0.003	0.01	mA	2

¹ Guaranteed by design and characterization, not 100% tested in production.

² Input clock stopped.

Electrical Characteristics–Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T_{AMB}. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

TAMB, Supply Voltagos per homai opolation conditione, Soci Foot Leade for Leading Conditione							
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
PLL Bandwidth	BW	-3dB point in High BW Mode (100MHz)	2.3	3.6	4.7	MHz	1,5
FLL Bandwidth	DVV	-3dB point in Low BW Mode (100MHz)	1	1.6	2.5	MHz	1,5
PLL Jitter Peaking	t _{JPEAK}	Peak Pass band Gain (100MHz)		1.3	2.5	dB	1
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50	55	%	1
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode	-1	-0.6	0	%	1,3
Skew, Input to Output	t _{pdBYP}	Bypass Mode, V _T = 50%	MHz) 1 1.6 2.5 MHz 1,5 iz) 1.3 2.5 dB 1 ode 45 50 55 % 1 Mode -1 -0.6 0 % 1,5 3400 4301 5200 ps 1 0 50 150 ps 1,4 37 75 ps 1,4	ps	1		
Skew, Input to Output	t _{pdPLL}	PLL Mode $V_T = 50\%$		1,4			
Skew, Output to Output	t _{sk3}	V _T = 50%		37	75	ps	1,4
littor. Ovala ta avala	+	PLL mode		24	50	ps	1,2
Jitter, Cycle to cycle	t _{jcyc-cyc}	Additive Jitter in Bypass Mode		0.1	10	ps	1,2

¹ Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

⁴ All outputs at default slew rate

⁵ The MIN/TYP/MAX values of each BW setting track each other, i.e., Low BW MAX will never occur with Hi BW MIN.

Electrical Characteristics–Phase Jitter Parameters

 $TA = T_{AMB}$, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

						INDUSTRY		
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	LIMIT	UNITS	Notes
	t _{jphPCleG1}	PCIe Gen 1		30	58	86	ps (p-p)	1,2,3,5
Phase Jitter, PLL Mode	+	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.9	1.4	3	ps (rms)	1,2,3,5
	t _{jphPCleG2}	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.1	2.6	3.1	ps (rms)	1,2,3,5
	t _{jphPCleG3}	PCIe Gen 3 Common Clock Architecture (PLL BW of 2-4 or 2-5MHz, CDR = 10MHz)		0.5	0.6	1	ps (rms)	1,2,3,5
	t _{jphPCleG3SRn} S	PCIe Gen 3 Separate Reference No Spread (SRnS) (PLL BW of 2-4 or 2-5MHz, CDR = 10MHz)		0.5	0.6	0.7	ps (rms)	1,2,3,5
	t _{jphPCleG1}	PCIe Gen 1		0.1	5	N/A	ps (p-p)	1,2,3,5
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.1	0.5	N/A	ps (rms)	1,2,3,4, 5
	t _{jphPCleG2}	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.1	0.7	N/A	ps (rms)	1,2,3,4
Additive Phase Jitter, Bypass Mode	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4 or 2-5MHz, CDR = 10MHz)		0.2	0.3	N/A	ps (rms)	1,2,3,4
	t _{jph125M0}	125MHz, 1.5MHz to 10MHz, -20dB/decade rollover < 1.5MHz, -40db/decade rolloff > 10MHz		200	250	N/A	fs (rms)	1,6
	t _{jph125M1}	125MHz, 12KHz to 20MHz, -20dB/decade rollover < 1.5MHz, -40db/decade rolloff > 10MHz		313	350	N/A	fs (rms)	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

² See http://www.pcisig.com for complete specs

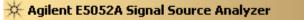
³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

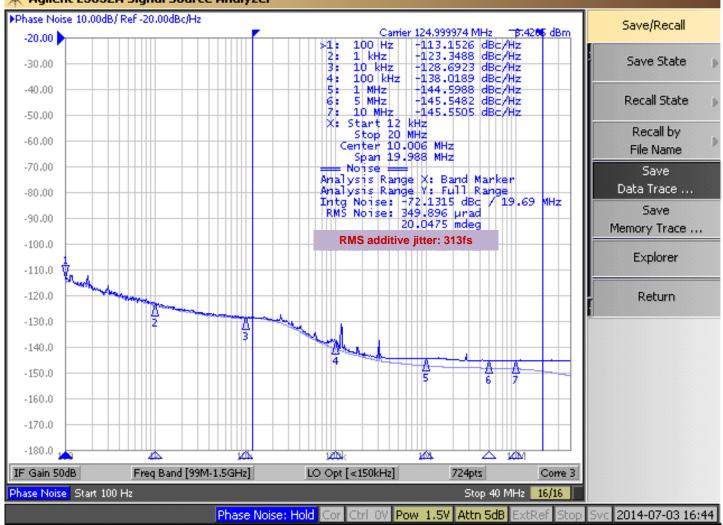
⁴ For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)^2 - (input jitter)^2]

⁵ Driven by 9FGU0831 or equivalent

⁶ Rohde&Schartz SMA100

Additive Phase Jitter Plot: 125M (12kHz to 20MHz)





General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) sends the byte count = X
- IDT clock will **acknowledge**
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Bl	ock \	Write Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	ig Byte N		
			ACK
0		×	
0		X Byte	0
0		Φ	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note: SMBus Address is Latched on SADR pin.

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block F	Read O	peration
Cor	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
SI	ave Address	_	
WR	WRite		
			ACK
Begi	nning Byte = N	-	
		-	ACK
RT	Repeat starT	-	
SI	ave Address		
RD	ReaD		
			ACK
		_	
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK	_	
		ę	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		

SMBus Table: Output Enable Register ¹

Byte 0	Name	Control Function	Туре	0	1	Default
Bit 7	DIF OE7	Output Enable	RW	Low/Low	Enabled	1
Bit 6	DIF OE6	Output Enable	RW	Low/Low	Enabled	1
Bit 5	DIF OE5	Output Enable	RW	Low/Low	Enabled	1
Bit 4	DIF OE4	Output Enable	RW	Low/Low	Enabled	1
Bit 3	DIF OE3	Output Enable	RW	Low/Low	Enabled	1
Bit 2	DIF OE2	Output Enable	RW	Low/Low	Enabled	1
Bit 1	DIF OE1	Output Enable	RW	Low/Low	Enabled	1
Bit 0	DIF OE0	Output Enable	RW	Low/Low	Enabled	1

1. A low on these bits will overide the OE# pin and force the differential output Low/Low

SMBus Table: PLL Operating Mode and Output Amplitude Control Register

Byte 1	Name	Control Function	Туре	0	1	Default
Bit 7	PLLMODERB1	PLL Mode Readback Bit 1	R	See PLL Operating Mode Table		Latch
Bit 6	PLLMODERB0	PLL Mode Readback Bit 0	R	See FLL Operat	Latch	
Bit 5	PLLMODE_SWCNTRL	Enable SW control of PLL Mode	RW	Values in B1[7:6]	Values in B1[4:3]	0
ыгэ	TELMODE_SWONTRE		1.1.1	set PLL Mode	set PLL Mode	J J
Bit 4	PLLMODE1	PLL Mode Control Bit 1	RW ¹	See PLL Operating Mode Table		0
Bit 3	PLLMODE0	PLL Mode Control Bit 0	RW ¹	See FLL Operat	ing mode rable	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.55V	01= 0.65V	1
Bit 0	AMPLITUDE 0	Controls Output Amplitude	RW	10 = 0.7V	11 = 0.8V	0

1. B1[5] must be set to a 1 for these bits to have any effect on the part.

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Туре	0	1	Default
Bit 7	SLEWRATESEL DIF7	Adjust Slew Rate of DIF7	RW	Slow Setting	Fast Setting	1
Bit 6	SLEWRATESEL DIF6	Adjust Slew Rate of DIF6	RW	Slow Setting	Fast Setting	1
Bit 5	SLEWRATESEL DIF5	Adjust Slew Rate of DIF5	RW	Slow Setting	Fast Setting	1
Bit 4	SLEWRATESEL DIF4	Adjust Slew Rate of DIF4	RW	Slow Setting	Fast Setting	1
Bit 3	SLEWRATESEL DIF3	Adjust Slew Rate of DIF3	RW	Slow Setting	Fast Setting	1
Bit 2	SLEWRATESEL DIF2	Adjust Slew Rate of DIF2	RW	Slow Setting	Fast Setting	1
Bit 1	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	Slow Setting	Fast Setting	1
Bit 0	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	Slow Setting	Fast Setting	1

Note: See "Low-Power HCSL Outputs" table for slew rates.

SMBus Table: Frequency Select Control Register

Byte 3	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved				1
Bit 6		Reserved				
Bit 5		Reserved				
Bit 4	Reserved					0
Bit 3	Reserved					0
Bit 2	Reserved					1
Bit 1	Reserved					1
Bit 0	SLEWRATESEL FB	Adjust Slew Rate of FB	RW	Slow Setting	Fast Setting	1

Byte 4 is Reserved and reads back 'hFF

SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Туре	0	1	Default
Bit 7	RID3		R	A rev		0
Bit 6	RID2	Revision ID	R			0
Bit 5	RID1	Revision	R			0
Bit 4	RID0		R		1	
Bit 3	VID3		R			0
Bit 2	VID2	VENDOR ID	R	0001		0
Bit 1	VID1		R	- 0001 = IDT		0
Bit 0	VID0		R			1

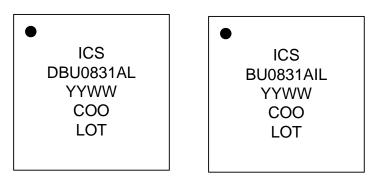
SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Туре	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGx, 01 =	DBx ZDB/FOB,	0
Bit 6	Device Type0	Device Type	R	10 = DMx, 1	1	
Bit 5	Device ID5		R	R	0	
Bit 4	Device ID4		R			0
Bit 3	Device ID3	Device ID	R	001000 bina	ny or 08 bey	1
Bit 2	Device ID2		R			0
Bit 1	Device ID1		R			0
Bit 0	Device ID0		R			0

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Туре	0	1	Default	
Bit 7	Reserved						
Bit 6	Reserved						
Bit 5	Reserved						
Bit 4	BC4		RW			0	
Bit 3	BC3		RW	Writing to this regist	er will configure how	1	
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	ead back, default is	0	
Bit 1	BC1		RW	= 8 b	ytes.	0	
Bit 0	BC0		RW			0	

Marking Diagrams



Notes:

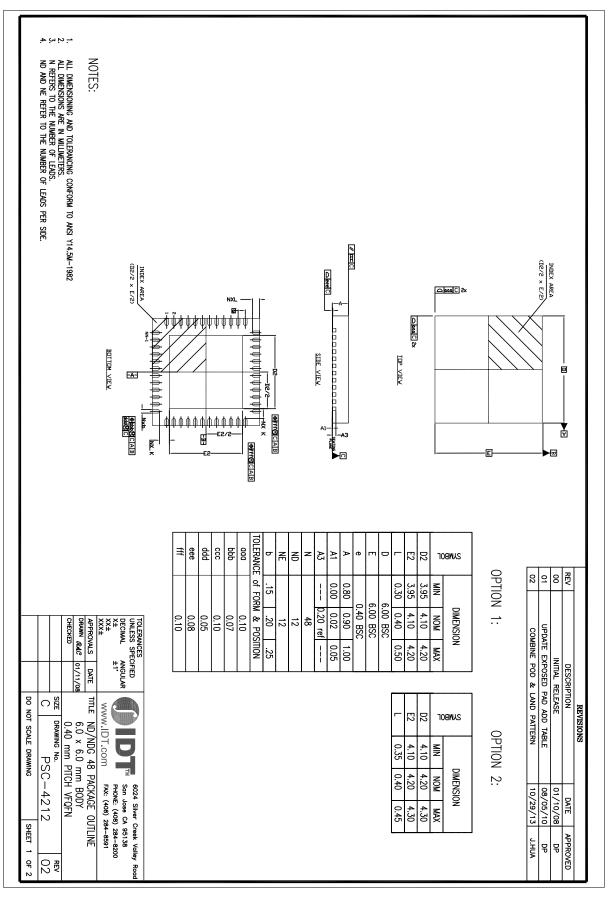
- 1. "LOT" is the lot sequence number.
- 2. "COO" denotes country of origin.
- 3. YYWW is the last two digits of the year and week that the part was assembled.
- 4. Line 2: truncated part number
- 5. "L" denotes RoHS compliant package.
- 6. "I" denotes industrial temperature range device.

Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
	θ _{JC}	Junction to Case	NDG48 33 2.1 37 30 27 26	33	°C/W	1
	θ_{Jb}	Junction to Base		2.1	°C/W	1
Thermal Resistance	θ _{JΑ0θ}	Junction to Air, still air		37	°C/W	1
mermai nesistance	θ_{JA1}	Junction to Air, 1 m/s air flow		°C/W	1	
	θ_{JA3}	Junction to Air, 3 m/s air flow		27	°C/W	1
	θ_{JA5}	Junction to Air, 5 m/s air flow		26	°C/W	1

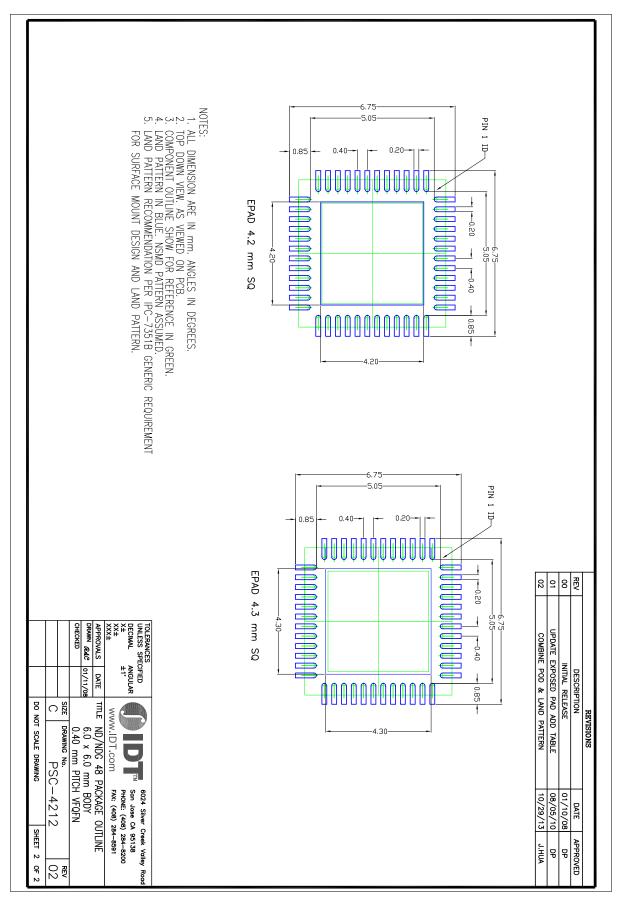
¹ePad soldered to board





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Package Outline and Package Dimensions (NDG48) - use EPAD 4.2 mm SQ



Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9DBU0831AKLF	Trays	48-pin VFQFPN	0 to +70° C
9DBU0831AKLFT	Tape and Reel	48-pin VFQFPN	0 to +70° C
9DBU0831AKILF	Trays	48-pin VFQFPN	-40 to +85° C
9DBU0831AKILFT	Tape and Reel	48-pin VFQFPN	-40 to +85° C

"LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant. "A" is the device revision designator (will not correlate with the datasheet revision).

Revision History

Rev.	Issue Date	Initiator	Description	
	RDW	//14/2014	1. Updated electrical tables with char data.	
А			 Added an additive phase jitter plot. Added 12kHz to 20MHz additive phase jitter spec. 	
			4. Updated Amplitude control bit <i>descriptions</i> in Byte 1.	
В	RDW	9/19/2014	Updated SMBus Input High/Low parameters conditions, MAX values, and footnotes.	
Ь				
	RDW	4/17/2015	1. Updated Key Specifications to be consistent acrosss the family.	
			2. Updated pin out and pin descriptions to show ePad on package	
С			connected to ground.	1-6
			3. Updated Clock Input Parameters table to be consistent with PCIe	
			Vswing parameter.	



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